Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S20	1161	(257/197).CCLS.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/02/14 18:11
S21	377	257/197.ccls. and ((back or back side) with (gate or electrode or conductor or contact))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/14 18:13
S22	91	257/197.ccls. and ((back or backside) with (gate or electrode or conductor or contact))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/14 18:13
S12	40	257/565.ccls. and (back with (electrode or gate))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/02/15 18:18
S23	46	257/565.ccls. and ((back or backside) with (electrode or gate))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/02/15 18:18
S14	45	257/565.ccls. and (inversion)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/02/15 18:25
S24	127	257/565.ccls. and ((inversion or charge) with (layer or region))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/02/15 18:25
S15	48	(257/587 and 257/592).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/02/15 18:40
S25	55	(257/587 and 257/592).ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 18:41
S16	170	(257/526).ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/02/15 18:46

S26	200	(257/526).ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/15 18:46
S17	54	semiconductor and SOI and ((back$5 or buried) with (gate or electrode)) and inversion and (vertical$5 with bipolar)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/02/15 19:10
S27	56	semiconductor and SOI and ((back$4 or buried) with (gate or electrode)) and inversion and (vertical$5 with bipolar)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/16 16:25
S28	1	semiconductor and SOI and ((back$4 or buried) with (gate or electrode)) and inversion and bipolar and ((base or collector) with rais$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/16 16:26
S29	27	semiconductor and SOI and ((back$4 or buried) with (gate or electrode)) and bipolar and ((base or collector) with rais$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/16 18:19
S30	77	semiconductor and SOI and bipolar and ((base or collector) with rais$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/16 18:20
S32	50	semiconductor and SOI and bipolar and ((base or collector) with rais$3) not S29	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/02/16 18:20